IXYS UK WESTCODE

Date:- 15th July, 2017

Data Sheet Issue:- A2

Rectifier Diode

Types W6360EC520 to W6360EC600

Development part number WX467EC600

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	5200-6000	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	5300-6100	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=55°C, (note 2)	6395	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 2)	4360	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 3)	2115	A
$I_{F(RMS)M}$	Nominal RMS forward current, T_{sink}=25°C, (note 2)	11770	A
$I_{F(d.c.)}$	D.C. forward current, T_{sink}=25°C, (note 4)	10860	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	60.6	kA
I_{FSM2}	Peak non-repetitive surge t_p=10ms, $V_{rm}\leq$10V, (note 5)	66.6	kA
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	18.4×10^6	A^2s
I^2t	I^2t capacity for fusing t_p=10ms, $V_{rm}\leq$10V, (note 5)	22.2×10^6	A^2s
$T_{j\,op}$	Operating temperature range	-40 to +150	°C
T_{stg}	Storage temperature range	-55 to +150	°C

Notes:-
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Anode side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 150°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	1.40	I_{FM}=4000A	V
V_{FM}	Maximum peak forward voltage	-	-	1.72	I_{FM}=6400A	V
V_{T0}	Threshold voltage	-	-	0.836		V
r_T	Slope resistance	-	-	0.135		mΩ
I_{RRM}	Peak reverse current	-	-	120	Rated V_{RRM}	mA
Q_{rr}	Recovered charge	-	24.0	26.5		mC
Q_{ra}	Recovered charge, 50% Chord	-	13.1	-	I_{TM}=1000A, t_p=1000µs, di/dt=10A/µs, V_r=100V	mC
I_{rm}	Reverse recovery current	-	360	-		A
t_{rr}	Reverse recovery time, 50% chord	-	73	-		µs
R_{thJK}	Thermal resistance, junction to heatsink	-	-	5.0	Double side cooled	K/kW
		-	-	15.3	Anode side cooled	K/kW
		-	-	7.6	Cathode side cooled	K/kW
F	Mounting force	72	-	88	Note 2	kN
W_t	Weight		1.6			kg

Notes:-
1) Unless otherwise indicated T_j=150°C.
2) For other clamp forces, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
52	5200	5300	3450
56	5600	5600	3730
60	6000	6100	4000

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{\,2} + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

and:

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_K$$

Where V_{T0}=0.836 V, r_T=0.135 mΩ,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.00547	0.00537	0.00527	0.00500
Square wave Anode Side Cooled	0.01578	0.01568	0.01558	0.01530
Square wave Cathode Side Cooled	0.00812	0.00803	0.00793	0.00760
Sine wave Double Side Cooled	0.00541	0.00531	0.00516	
Sine wave Anode Side Cooled	0.01573	0.01562	0.01547	
Sine wave Cathode Side Cooled	0.00807	0.00797	0.00783	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;
(i) the well established V_{T0} and r_T tangent used for rating purposes and
(ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	150°C Coefficients
A	0.7180761	0.5701565
B	0.01268471	-0.01677961
C	4.98395×10^{-5}	5.20409×10^{-5}
D	4.90909×10^{-3}	0.0120222

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where *p = 1* to *n, n* is the number of terms in the series and:
t = Duration of heating pulse in seconds.
r_t = Thermal resistance at time t.
r_p = Amplitude of p_{th} term.
τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	1.814569×10^{-3}	1.387758×10^{-3}	1.396203×10^{-3}	4.166929×10^{-4}
τ_p	0.8935959	0.3520884	0.05967738	0.01884303

D.C. Anode Side Cooled			
Term	1	2	3
r_p	0.01298525	1.740643×10^{-3}	6.018416×10^{-4}
τ_p	4.049550	0.08994614	0.02080296

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	3.692153×10^{-3}	1.972318×10^{-3}	8.564712×10^{-4}	1.158361×10^{-3}
τ_p	5.385607	0.4218774	0.0982282	0.03161376

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. 1

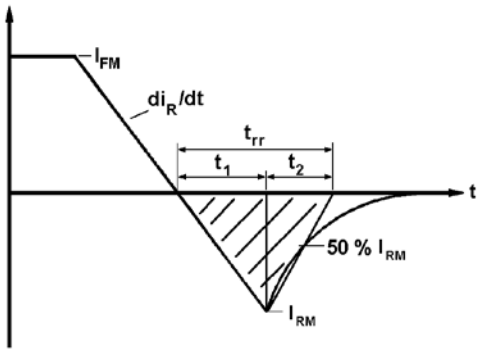

Fig. 1

(ii) Q_{rr} is based on a 150μs integration time i.e.

$$Q_{rr} = \int_0^{150\,\mu s} i_{rr}.dt$$

(iii)

$$K\ Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 – Forward characteristics of Limit device

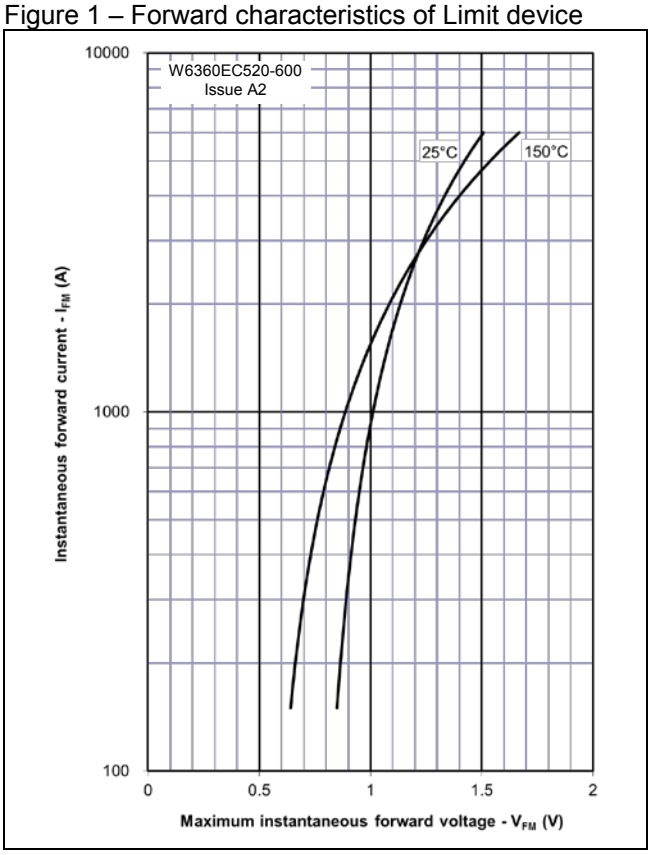

Figure 2 – Transient thermal impedance

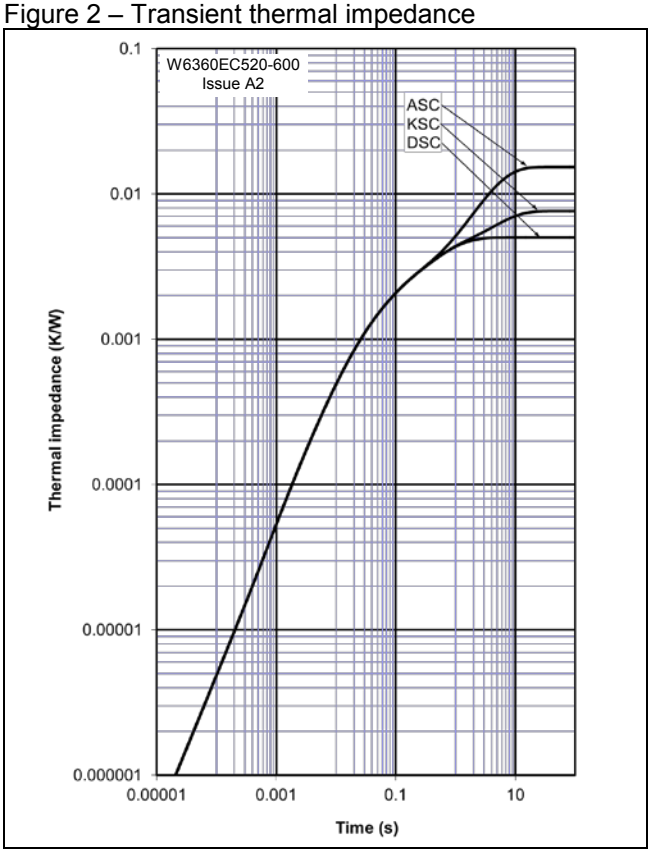

Figure 3 – Maximum Surge Rating

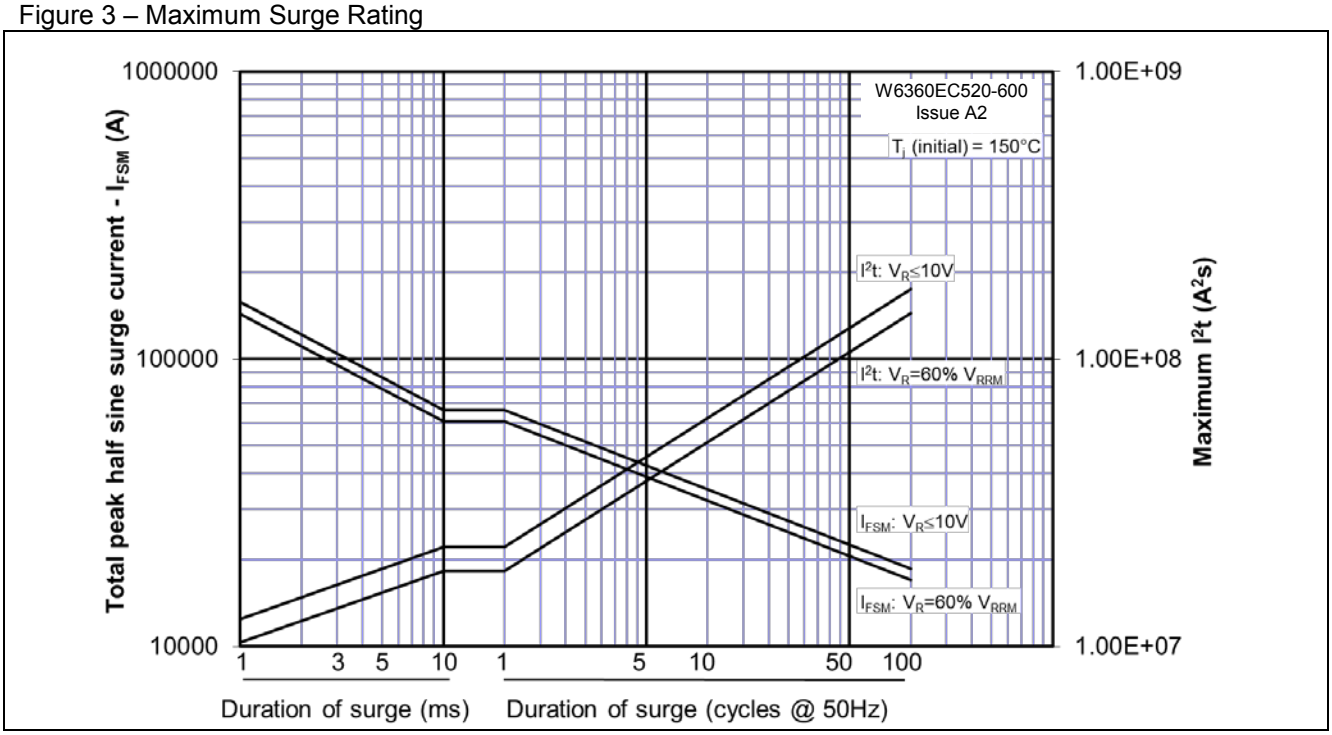

Figure 4 – Total recovered charge, Q_{rr}

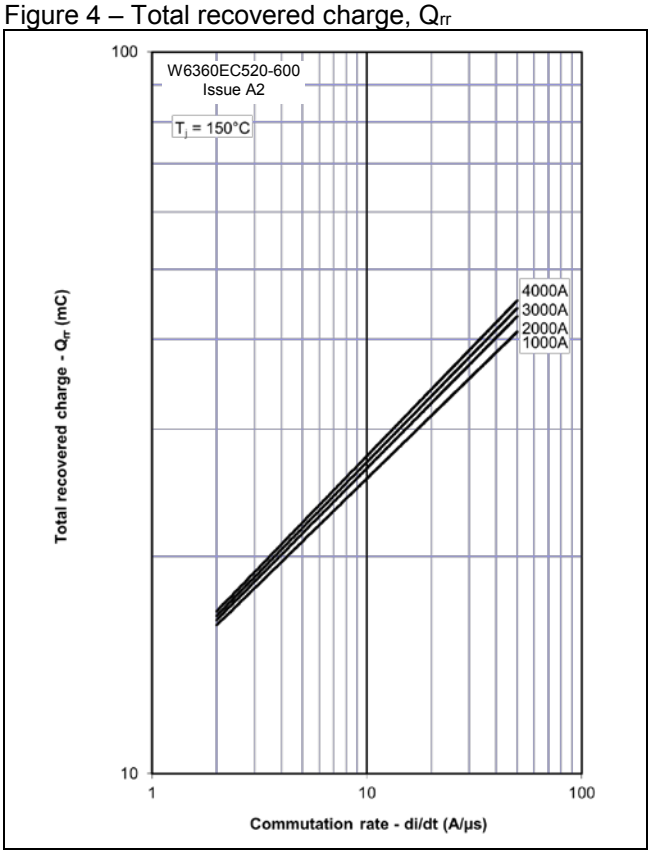

Figure 5 – Recovered charge, Q_{ra} (50% chord)

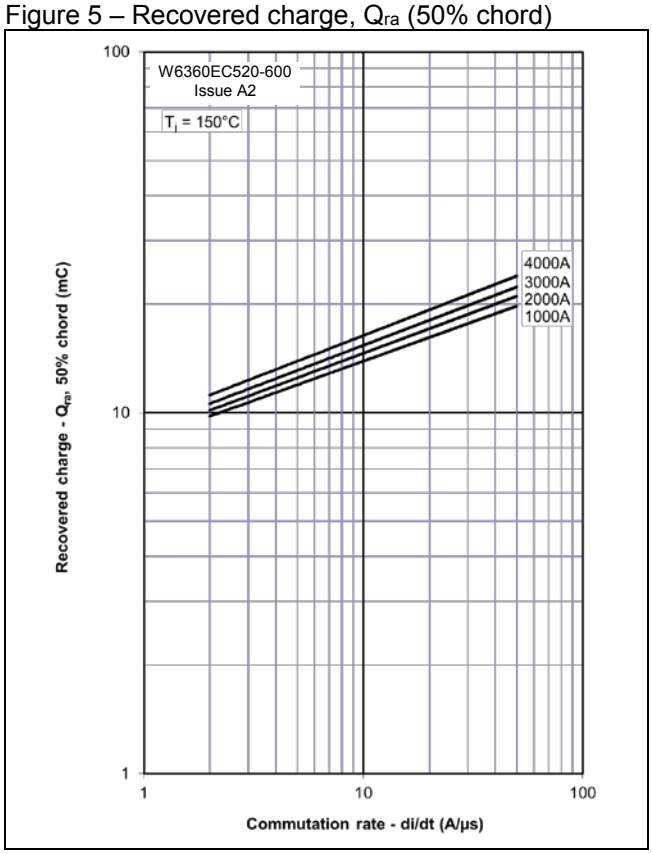

Figure 6 – Peak reverse recovery current, I_{rm}

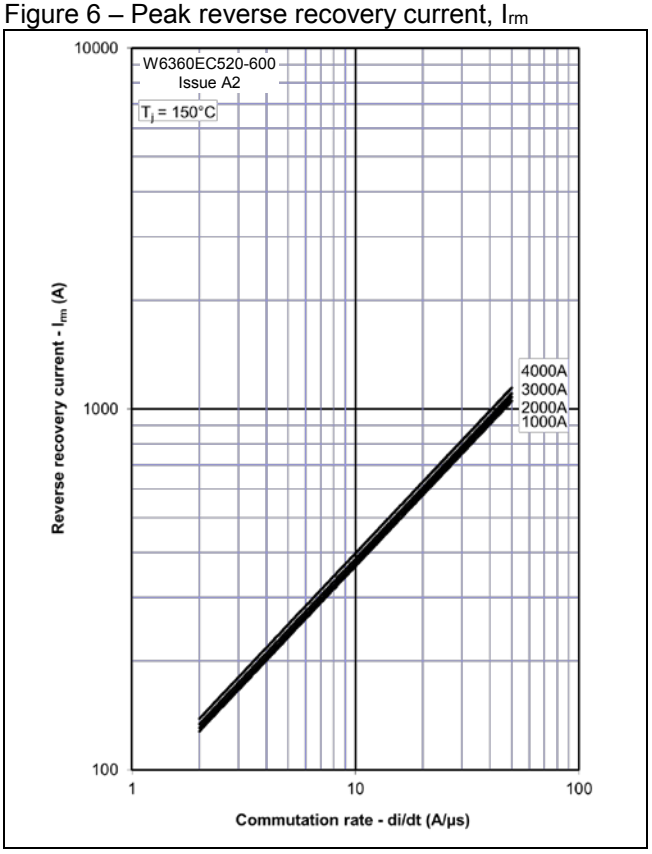

Figure 7 – Maximum recovery time, t_{rr} (50% chord)

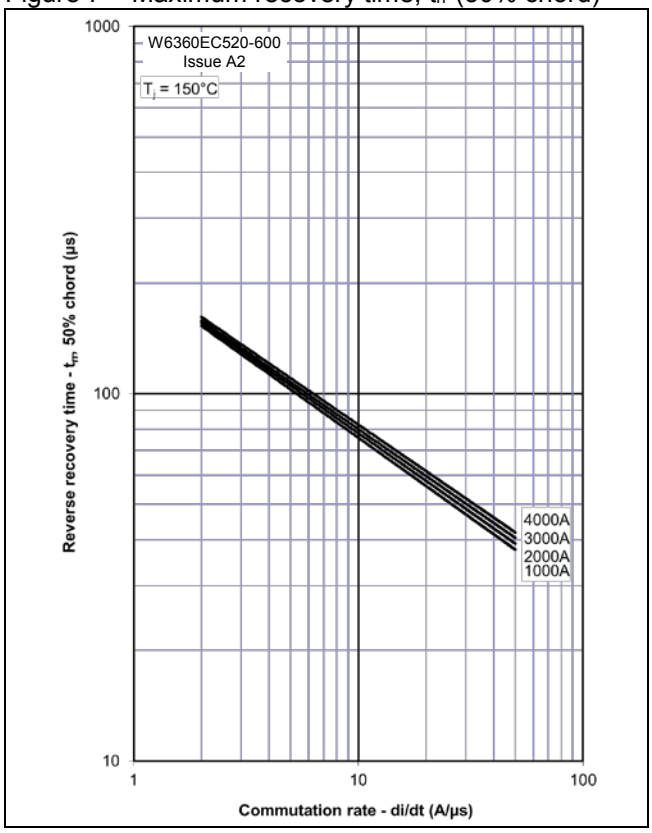

Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

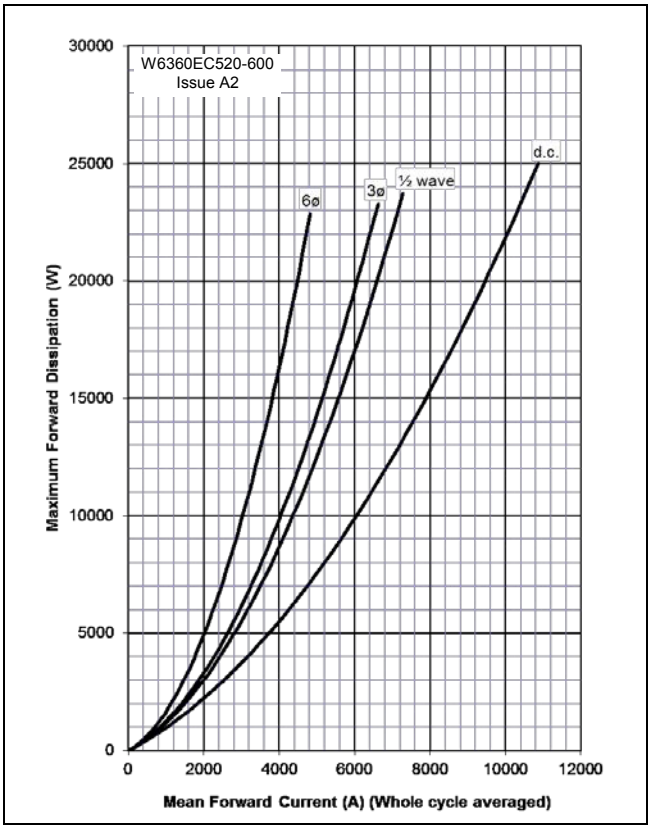

Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled

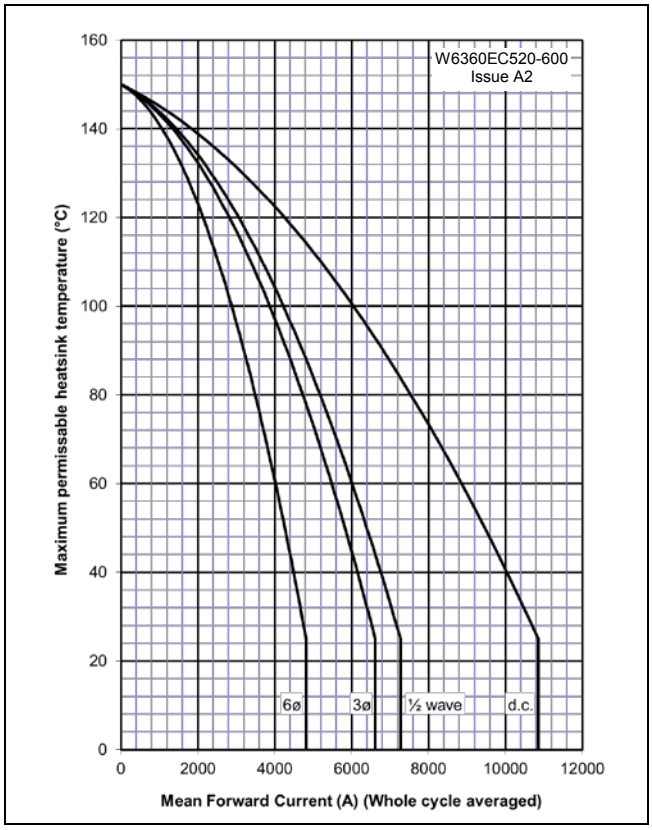

Figure 10 – Forward current vs. Power dissipation – Cathode Side Cooled

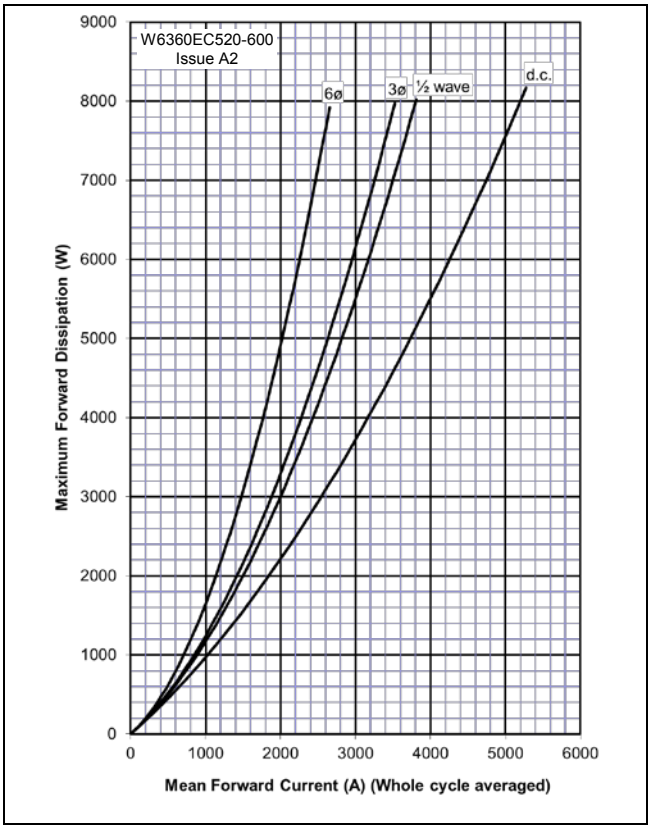

Figure 11 – Forward current vs. Heatsink temperature – Cathode Side Cooled